

60V 175°C N-CHANNEL ENHANCEMENT MODE MOSFET

PowerDI5060-8

Product Summary

BV _{DSS}	Rds(on) Max	I⊳ Max Tc = +25°C (Note 7)
60)/	3.1mΩ @ V _{GS} = 10V	100A
60V	4.5mΩ @ V _{GS} = 4.5V	100A

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Primary switches in isolated DC-DC
- Synchronous rectifiers
- Load switches

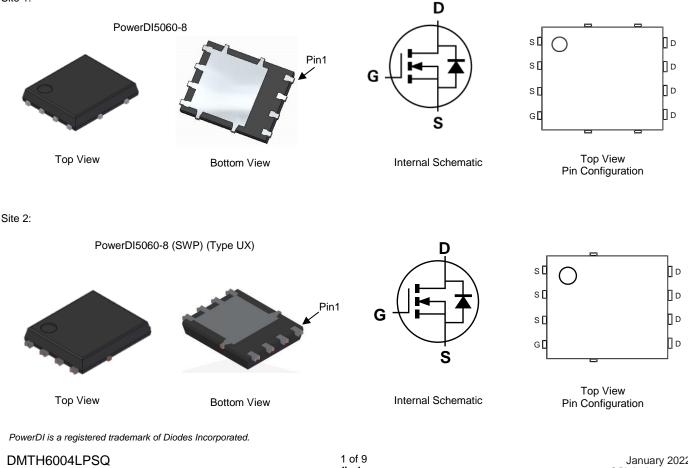
Features

- Rated to +175°C Ideal for High Ambient Temperature • Environments
- 100% Unclamped Inductive Switching (UIS) Test in Production -• Ensures More Reliable and Robust End Application
- Low RDS(ON) Minimizes Power Losses •
- Low Qg Minimizes Switching Losses
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMTH6004LPSQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Package: PowerDI[®]5060-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe; Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.097 grams (Approximate)



Document number: DS38165 Rev. 3 - 2

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Site 1:



Ordering Information (Note 4)

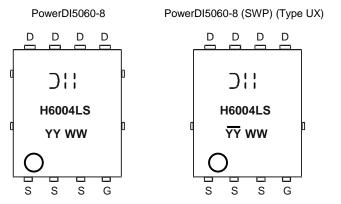
	Part Number	Baakaga	Packing			
	Fait Nulliper	Package	Qty.	Carrier		
	DMTH6004LPSQ-13	PowerDI5060-8	2,500	Tape & Reel		
	DMTH6004LPSQ-13 PowerDI5060-8 (SWP) (Type UX) 2,500 Tape & Reel					
Notes:	es: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.					

EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
 See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage		Vdss	60	V
Gate-Source Voltage		Vgss	±20	V
Continuous Drain Current (Note 5)	T _A = +25°C T _A = +70°C	ID	22 16	А
Continuous Drain Current (Notes 6 & 7)	Tc = +25°C Tc = +100°C	ID	100 100	А
Maximum Continuous Body Diode Forward Current (Note 5)		ls	100	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		Ідм	400	A
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)		lsм	400	A
Avalanche Current, L = 0.2mH		las	40	A
Avalanche Energy, L = 0.2mH		Eas	160	mJ

Thermal Characteristic

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T _A = +25°C	PD	2.6	W
Thermal Resistance, Junction to Ambient (Note 5)		Reja	47	°C/W
Total Power Dissipation (Note 6)	Tc = +25°C	PD	138	W
Thermal Resistance, Junction to Case (Note 6)		Rejc	0.9	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate. 6. Thermal resistance from junction to soldering point (on the exposed drain pad).

7. Limited by package.



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

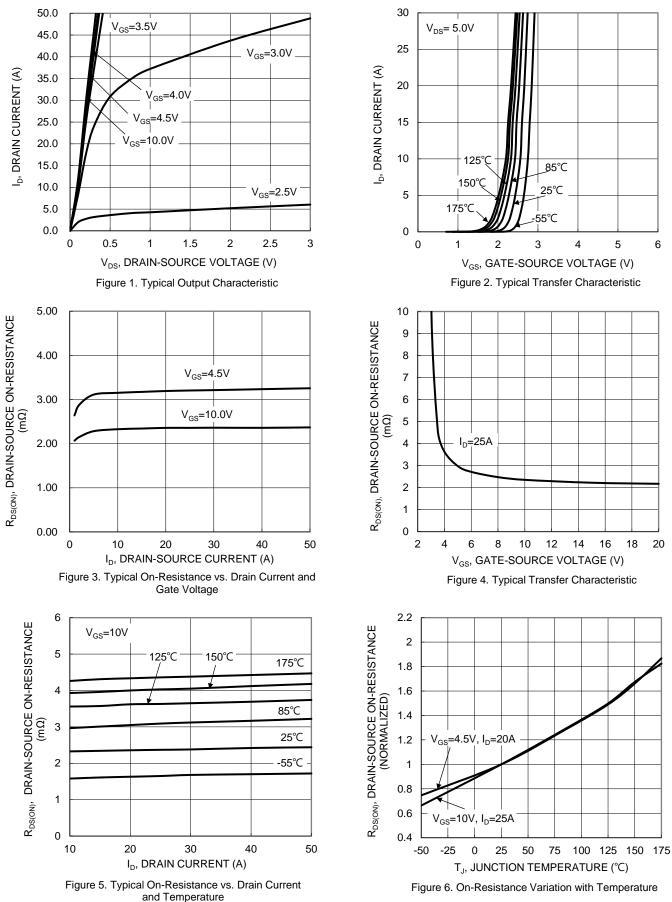
		-			-	-	
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BVDSS	60	_	—	V	$V_{GS} = 0V$, $I_D = 1mA$	
Zero Gate Voltage Drain Current	IDSS		—	1	μA	$V_{DS} = 48V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}		_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	Vgs(th)	1	_	3	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
Static Drain-Source On-Resistance	Bracous		2.5	3.1	mΩ	$V_{GS} = 10V, I_D = 25A$	
Static Drain-Source On-Resistance	Rds(on)		3.3	4.5	mΩ	$V_{GS} = 4.5V, I_D = 20A$	
Diode Forward Voltage	V _{SD}	_	_	1.3	V	$V_{GS} = 0V, I_{S} = 25A$	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	Ciss		5399	_	pF	V _{DS} = 30V, V _{GS} = 0V f = 1MHz	
Output Capacitance	Coss		1306	_			
Reverse Transfer Capacitance	Crss		92	-			
Gate Resistance	Rg		0.64	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V _{GS} = 10V)	Qg		78.3	-			
Total Gate Charge ($V_{GS} = 4.5V$)	Qg	_	38.5	—	nC	V _{DD} = 30V, I _D = 25A	
Gate-Source Charge	Q _{gs}	_	10.2	—			
Gate-Drain Charge	Q _{gd}	_	20.4	—			
Turn-On Delay Time	t _{D(ON)}	_	9.9	—			
Turn-On Rise Time	tR	_	17.7	—	ns	$V_{DD} = 30V, V_{GS} = 10V$ $I_D = 25A, R_g = 3.5\Omega$	
Turn-Off Delay Time	tD(OFF)		53.5	—			
Turn-Off Fall Time	tF		32.9	—	1		
Body Diode Reverse Recovery Time	trr		49.7	—	ns		
Body Diode Reverse Recovery Charge	Q _{RR}		78.9	—	nC	I _F = 25A, di/dt = 100A/μs	

 Notes:
 8. Short duration pulse test used to minimize self-heating effect.

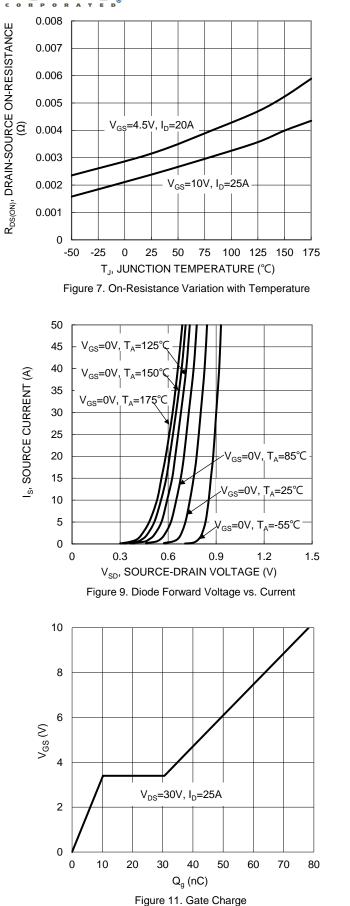
 9. Guaranteed by design. Not subject to production testing.

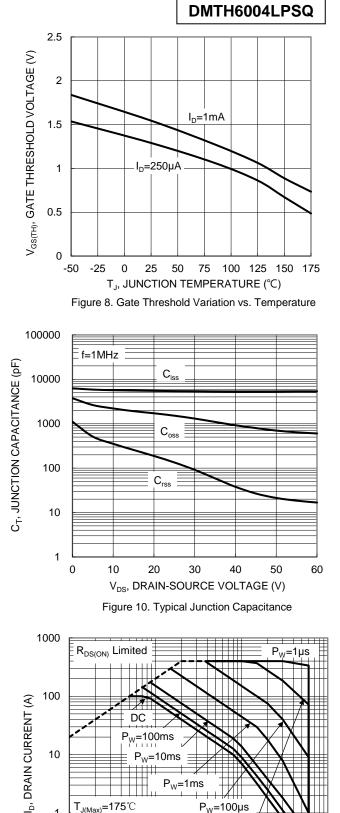


DMTH6004LPSQ









P_w=1ms

P_w=100µs

V_{DS}, DRAIN-SOURCE VOLTAGE (V)

Figure 12. SOA, Safe Operation Area

Ρ =10us

10

T_{J(Max)}=175℃

Single Pulse

DUT on Infinite Heatsink

1

T_C=25℃

V_{GS}=10V

1

0.1

0.1

100



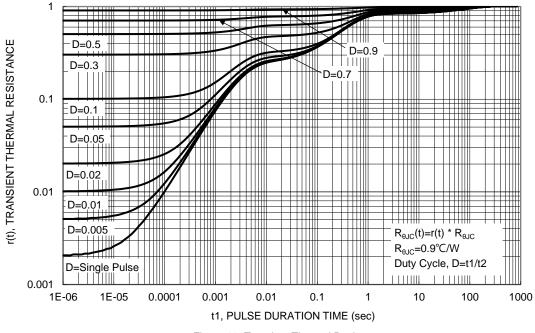


Figure 13. Transient Thermal Resistance

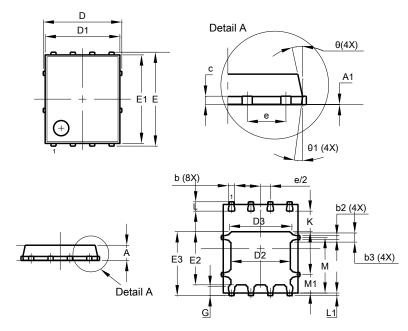


Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

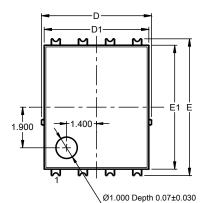
Site 1:

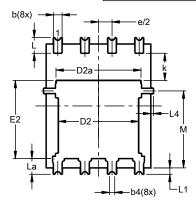




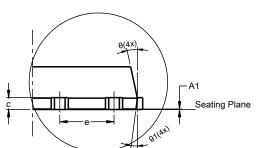
PowerDI5060-8					
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0.00	0.05	-		
b	0.33	0.51	0.41		
b2	0.200	0.350	0.273		
b3	0.40	0.80	0.60		
С	0.230	0.330	0.277		
D		5.15 BSC			
D1	4.70	5.10	4.90		
D2	3.70	4.10	3.90		
D3	3.90	4.30	4.10		
E	6.15 BSC				
E1	5.60	6.00	5.80		
E2	3.28	3.68	3.48		
E3	3.99	4.39	4.19		
е		1.27 BSC			
G	0.51	0.71	0.61		
К	0.51	-	-		
L	0.51	0.71	0.61		
L1	0.100	0.200	0.175		
М	3.235	4.035	3.635		
M1	1.00	1.40	1.21		
Θ	10°	12°	11°		
Θ1	6°	8°	7°		
All	All Dimensions in mm				

Site 2:

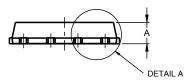




PowerDI5060-8 (SWP) (Type UX)



DETAIL A



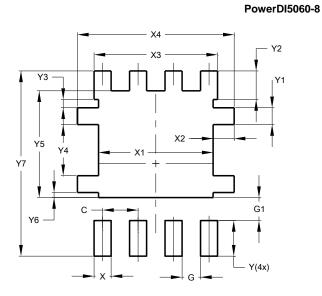
PowerDI5060-8 (SWP)					
(Type UX)					
Dim	Min Max Typ				
Α	0.90	1.10	1.00		
A1	0	0.05			
b	0.30	0.50	0.41		
b2	0.20	0.35	0.25		
b4	().25REF			
С	0.230	0.330	0.277		
D	5	.15 BS0	2		
D1	4.70	5.10	4.90		
D2	3.56	3.96	3.76		
D2a	3.78	4.18	3.98		
Е	6	.40 BS0	2		
E1	5.60	6.00	5.80		
E2	3.46	3.86	3.66		
E2a	4.195	4.595	4.395		
е	1	.27BSC)		
k	1.05				
L	0.635	0.835	0.735		
La	0.635	0.835	0.735		
L1	0.200	0.400	0.300		
L1a	0	.050RE	F		
L4	0.025	0.225	0.125		
М	3.205	4.005	3.605		
θ	10°	12°	11°		
θ1	6°	8°	7°		
All Dimensions in mm					



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

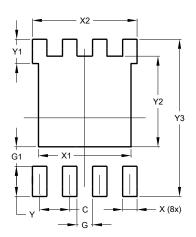
Site 1:



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	0.755
X3	4.420
X4	5.610
Y	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
Y7	6.610

Site 2:

PowerDI5060-8 (SWP) (Type UX)



Dimensions	Value (in mm)		
С	1.270		
G	0.660		
G1	0.820		
Х	0.610		
X1	4.100		
X2	4.420		
Y	1.270		
Y1	1.020		
Y2	3.810		
Y3	6.610		



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